

Current Transducer HAIS 50..400-P and HAIS 50..100-TP

For the electronic measurement of currents: DC, AC, pulsed, mixed, with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).



400







planned

All Data are given with a $R_L = 10$			
Electrical	data		
Primary nominal current rms I _{PN} (A)	Primary current, measuring range I _{PM} (A)	Туре	RoHS since date code
50 100	± 150 ± 300	HAIS 50-P, HAIS 50-TP ¹⁾ HAIS 100-P, HAIS 100-TP ¹⁾	45231, 46272 45231, 46012
150 200	± 450 ± 600	HAIS 150-P HAIS 200-P	46172 45231

HAIS 400-P

		F	
V _{OUT}	Output voltage (Analog) @ I _P	V _{REF} ±(0.625- I	_P / I _{PN}) V
	$\mathbf{I}_{p} = 0$	$V_{REF} \pm 0.025$	V
\mathbf{V}_{REF}	Reference voltage 2) - Output voltage	2.5 ± 0.025	V
	V _{RFF} Output impedance	typ. 200	Ω
	V _{REF} Load impedance	≥ 200	kΩ
$R_{_{1}}$	Load resistance	≥ 2	kΩ
R _{OUT}	Output internal resistance	< 10	Ω
C L	Capacitive loading	< 1	μF
V c	Supply voltage (± 5 %)	5	V
I c	Current consumption @ $V_c = 5 \text{ V}$	22	mΑ

Accuracy - Dynamic	performance data

 ± 600

Χ	Accuracy $^{3)}$ @ \mathbf{I}_{PN} , $\mathbf{T}_{A} = 25^{\circ}\mathrm{C}$	≤ ± 1	% of I _{PN}
$\mathbf{e}_{\scriptscriptstyle \perp}$	Linearity error 0 3 x I _{PN}	\leq ± 0.5	% of I _{PN}
TCV	Temperature coefficient of $\mathbf{V}_{OE} @ \mathbf{I}_{P} = 0$	\leq ± 0.3	mV/K
TCV _{REF}	Temperature coefficient of V _{REF}	\leq ± 0.01	%/K
TCV _{OUT} /V _{REF}	Temperature coefficient of $\mathbf{V}_{\text{OLIT}}/\mathbf{V}_{\text{REF}} @ \mathbf{I}_{\text{P}} = 0$	\leq ± 0.2	mV/K
TCV	Temperature coefficient of V _{OUT}	\leq ±0.05% of	f reading/K
V _{OM}	Magnetic offset voltage @ $I_p = 0$,		
	after an overload of 3 x I _{PN DC}	$< \pm 0.4$	% of $I_{_{\mathrm{PN}}}$
t _{ra}	Reaction time @ 10 % of I _{PN}	< 3	μs
t,	Response time to 90 % of I _{PN} step	< 5	μs
di/dt	di/dt accurately followed	> 100	A/μs
\mathbf{V}_{no}	Output voltage noise (DC10 kHz)	< 15	mVpp
	(DC 1 MHz)	< 40	mVpp
BW	Frequency bandwidth (-3 dB) 4)	DC 50	kHz

Notes: 1) -TP version is equipped with a primary bus bar.

- $^{\mbox{\tiny 2)}}$ It is possible to overdrive $\boldsymbol{V}_{\mbox{\tiny REF}}$ with an external reference voltage between 2 - 2.8 V providing its ability to sink or source approximately 2.5 mA.
- ³⁾ Excluding offset and hysteresis.
- ⁴⁾ Small signal only to avoid excessive heatings of the magnetic core.

= 50..400 A



Features

- Hall effect measuring principle
- Galvanic isolation between primary and secondary circuit
- Isolation test voltage 2500V
- Low power consumption
- Single power supply +5V
- Fixed offset & gain
- Bus bar version available for 50A and 100A ratings.
- Isolated plastic case recognized according to UL94-V0.

Advantages

- Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference.
- V_{REF.} IN/OUT

Applications

- AC variable speed drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

Application domain

• Industrial



Current Transducer HAIS 50..400-P and HAIS 50..100-TP

Gene	eral data				
T _A	Ambient operating temperature		- 40 +	85 °C	
T _s	Ambient storage temperature	The state of the s		- 40 + 85 °C	
m	Mass (in brackets : TP version)		20 (30)	g	
	Standards		EN 501	78: 1997	
Isola	tion characteristics				
V _b	Rated isolation voltage rms		300	V rms	
	with IEC 61010-1 standards and	following condition	S		
	 Single insulation 				
	 Over voltage category III 				
	- Pollution degree 2				
	- Heterogeneous field				
$V_{_{\rm b}}$	Rated isolation voltage rms		600	V rms	
	with EN 50178 standards and fo	llowing conditions			
	- Reinforced insulation				
	- Over voltage category III				
	- Pollution degree 2				
	- Heterogeneous field				
V _d	Rms voltage for AC isolation tes		2.5	kV	
$V_{_{\mathrm{e}}}$	Partial discharge extinction volta	•		137	
		HAIS 50400-P	>1	kV	
ŵ	languilan with stand waltans 4.0/5	HAIS 50100-TP		kV	
Ŷ _w	Impulse withstand voltage 1.2/5	υμs	8	kV	
dCp	Creepage distance		> 8	m m	
dCI CTI	Clearance distance		> 8	m m	
CII	Comparative tracking index (Gro	up i)	> 600		
	If insulated cable is used for the	nrimary circuit the			
	voltage category could be impro	•			
	Cable insulation (primary)	Category	ing table	•	
	HAR 03	450V CAT III			
	HAR 05	550V CAT III			
	HAR 07	650V CAT III			
		230. 0			

Safety



This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the following manufacturer's operating instructions.



Caution! Risk of electrical shock

When operating the transducer, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply).

Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a built-in device, whose conducting parts must be inaccessible after installation.

A protective housing or additional shield could be used.

Main supply must be able to be disconnected.

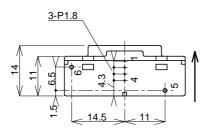


Dimensions HAIS 50..400-P and HAIS 50..100-TP (in mm. 1 mm = 0.0394 inch)

HAIS 50..400-P

Front view 33 15 2-D1.0 4-0.25x0.45

Bottom view



Terminal Pin Identification

- 1...+5V
- 2...0V
- 3...OUTPUT
- 4...Vref. (IN/OUT)
- 5...Core Earth (*)
- 6...NC.

Recommended PCB hole

Pin 1-4: 0.7 ±0.1mm Pin 5-6: 1.5 ±0.1mm

Primary bus bar: 2.3 ±0.1mm

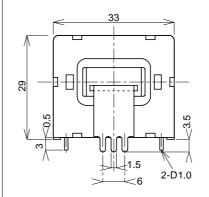
General tolerance: ±0.2mm

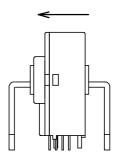
Unit: mm

HAIS 50..100-TP

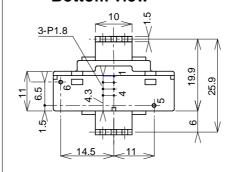
Front view

Right view

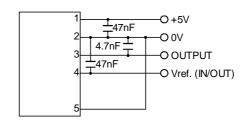




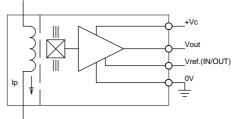
Bottom view



Required Connection Circuit



Operation Principle



^(*) should be connected to 0V of Power Supply for better dv/dt immunity. Arrow indicates positive current direction.